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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of

Heemyong Park et al.

Confirmation No.: 3592

Serial No.: 09/924,318

Group Art Unit: 1765

Filed: August 8, 2001

Examiner: B. Tran

For: METHOD OF BUILDING A CMOS STRUCTURE ON THIN SOI
WITH SOURCE/DRAIN ELECTRODES FORMED IN SITU

Commissioner for Patents
United States Patent and Trademark Office
P. O. Box 1450
Alexandria, Virginia 22313-1450

AMENDMENT UNDER 37 C. F. R. §1.111

Sir:

In response to the Office Action mailed August 26, 2003, please amend the above-identified application as follows:

Amendments to the specification begin on page 2 of this paper.

Amendments to the claims begin on page 3 of this paper.

Amendments to the Drawings begin on page 5 of this paper and include an attached replacement drawing sheet.

Remarks begin on page 6 of this paper.